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## Enhanced Magneto-optic Kerr Effect and Magnetic Properties of $\text{CeY}_2\text{Fe}_5\text{O}_{12}$ Epitaxial Thin Films

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The magnetic and magneto-optic properties of epitaxial  $\text{CeY}_2\text{Fe}_5\text{O}_{12}$  (Ce:YIG) and  $\text{Y}_3\text{Fe}_5\text{O}_{12}$  (yttrium iron garnet or YIG) thin films grown by pulsed laser deposition on gadolinium gallium garnet substrates are determined. An enhanced Faraday effect is known to result from Ce substitution into the yttrium iron garnet lattice, and here we characterize the magneto-optic Kerr effect, as well as the magnetic hysteresis and ferromagnetic resonance response that result from the Ce substitution. X-ray diffraction analysis reveals a high crystallographic quality for the Ce:YIG films. Measurements of the magneto-optic Kerr effect for two different wavelengths demonstrate that the Ce:YIG exhibits an up-to-tenfold increase in Kerr rotation compared to YIG. The Ce:YIG has a slightly larger magnetic moment, as well as increased magnetic damping and higher magnetic anisotropy compared to YIG with a dependence on the crystalline orientation. By specific cerium substitution in YIG, our results show that the engineering of a large Kerr effect and tailored magnetic anisotropy becomes possible as required for magneto-optically active spintronic devices.

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### I. INTRODUCTION

Over 50 years ago, the discovery of yttrium iron garnet [1,2] ( $\text{Y}_3\text{Fe}_5\text{O}_{12}$  or YIG) led to remarkable advances in microwave technology. The combination of low magnetic damping, soft magnetization behavior, and a band gap of 2.66 eV, making it a good insulator, qualify this material for microwave applications such as filters [3,4] or sensors [5,6]. Its low absorption in the optical and near-infrared wavelength region, combined with a magneto-optic Faraday effect (FE), render this material interesting for telecommunication devices such as magneto-optic isolators [7,8]. For such applications, a higher FE is desirable, which allows for the miniaturization of the device [7,9]. With the substitution of yttrium with bismuth or rare earth elements such as cerium, it is possible to enhance the FE with only small changes of magnetic moment [10,11], while the garnet maintains its important property as an electrical insulator. The influence of the substitution of bismuth on the magneto-optic properties has been investigated intensively [12–15], while for cerium only the FE has been studied in bulk [16–18] and to a lesser extent for thin films [19–23]. However, studies have not been carried out on the magneto-optic Kerr effect (MOKE) in Ce:YIG, which is

relevant for magneto-optic readout applications that are based on reflection geometry. As the MOKE in YIG is known to be small for wavelengths in the red and near-infrared spectral range, used for optical communications, Ce:YIG thin films are potentially promising, but the MOKE in Ce:YIG needs to be characterized in this wavelength range. An understanding of the magnetic and magneto-optic Kerr behavior of Ce:YIG thin films will facilitate the development of insulating, nonreciprocal, magneto-optic devices, as well as MOKE studies of magnetic phenomena in thin films, such as imaging of eigenmodes in garnets [24,25], which is of particular interest for the development of spin-wave logic [26].

Previously, the effect of cerium substitution on the ferromagnetic resonance (FMR) has been studied, but no reliable reports of the resulting changes in damping have been published due the challenge of growing Ce:YIG without the formation of  $\text{CeO}_2$  phases, which disturb the FMR signal [17]. A combination of a strong MOKE signal and low magnetic damping in an insulating material would not only be of interest for magneto-optic applications. This would also allow one to investigate novel phenomena such as domain-wall motion in a magnetic insulator, which is in contrast to the well-established domain-wall motion in conductors, not driven by electronic spin currents [27] but by spin waves [28,29]. Recent results in the field of spin caloritronics have shown that the spin waves can also be

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thermally excited by the spin Seebeck effect [30] and are capable of moving magnetic domains [31–35]. However, a more detailed analysis of the thermally excited domain wall motion has not been possible, so far, as experimental observations are currently limited only to bulk materials due to the relatively weak signal in YIG. A stronger MOKE signal of Ce:YIG would enable even studies on thin-film nanostructures, which would allow one to gauge the applicability of domain-wall motion in memory or logic insulator devices.

Finally for possible applications in spintronics, the magnetic anisotropies, in particular, need to be controllable. For YIG and other iron garnets, strain has been found to allow the engineering of the anisotropies [36,37]. However, element substitution such as Ce doping could provide another approach, which has not been investigated so far but is of interest for all spintronic applications, in particular, for magneto-optic sensors [38,39]. Tailoring the anisotropy is key as it allows one to determine the orientation of the device.

In this article, we present a characterization of epitaxial Ce:YIG ( $\text{CeY}_2\text{Fe}_5\text{O}_{12}$ ) films by superconducting-quantum-interference-device (SQUID) magnetometry, MOKE, MOKE microscopy, FMR, as well as crystallographic analysis, and we compare the results with those of epitaxial YIG ( $\text{Y}_3\text{Fe}_5\text{O}_{12}$ ) thin films with different crystallographic orientations produced by pulsed laser deposition (PLD). The results reveal that, despite the lattice mismatch, Ce:YIG thin films can be grown with high quality epitaxially on gadolinium gallium garnet ( $\text{Gd}_3\text{Ga}_5\text{O}_{12}$  or GGG) substrates. An in-plane magnetic anisotropy can be introduced in this material, depending on the substrate cut. Compared to pure YIG, these materials show a slightly higher magnetic moment and, as an insulator, a damping comparable to magnetic metals. In particular, we find a strongly enhanced MOKE signal for visible wavelengths, making the cerium substitution useful for thin-film optical devices.

## II. EXPERIMENTAL METHODS

The YIG and Ce-substituted YIG films are deposited by PLD on single-crystal GGG substrates with (001) and (111) orientations from mixed powder targets of stoichiometry  $\text{Y}_3\text{Fe}_5\text{O}_{12}$  and  $\text{Ce}_1\text{Y}_2\text{Fe}_5\text{O}_{12}$ . For target fabrication, the powders are mixed at weights to match the desired stoichiometry and then ground by ball milling ( $\text{ZrO}_2$  balls) for 24 h. Next, the powder is sintered at  $1400^\circ\text{C}$  for 10 h. The target then is calcined at  $1150^\circ\text{C}$  for 12 h, to obtain the YIG or Ce:YIG phase [19,40].

The optimal deposition conditions for YIG are found for an oxygen deposition pressure of  $2.67 \times 10^{-2}$  mbar (20 mtorr), a substrate temperature of  $650^\circ\text{C}$ , and a laser pulse energy of 400 mJ (krypton fluoride (KrF),  $\lambda = 248$  nm) using a 10-Hz repetition rate. After the deposition, the YIG films are *ex situ* annealed at  $800^\circ\text{C}$

for 5 min, using rapid thermal annealing under a steady flow of pure oxygen [40].

For the Ce:YIG films grown at an optimized oxygen pressure of  $6.67 \times 10^{-3}$  mbar (5 mtorr), a substrate temperature of  $815^\circ\text{C}$  and the same pulse energy and repetition rate as for the YIG samples are used. In contrast to the YIG samples, the Ce:YIG samples are not annealed and only cooled down to room temperature at the deposition oxygen pressure. Ce:YIG films are not annealed after PLD growth to preserve the homogeneous distribution of cerium ions inside the YIG lattice. The crystallographic properties are analyzed using x-ray diffraction (XRD) and x-ray reflectivity (XRR) in a Bruker D8 diffractometer. The saturation moment of each sample is measured by SQUID (Quantum Design MPMSXL) at room temperature, while the coercive fields are probed by a vibrating sample magnetometer (VSM). To obtain the magnetic moment  $M_s$  of the film, a linear subtraction of the paramagnetic contribution of the GGG substrate background is done.

MOKE magnetometry measurements are carried out in an extended MOKE setup similar to the one described in Ref. [41], but with different wavelengths and a rotatable Wollaston prism combined with two photodiodes for polarization detection, as used in Ref. [42]. For the present study, we use linearly polarized light of 406 nm and 635 nm. The angle of incidence is  $45^\circ$  for the longitudinal geometry (in-plane external magnetic field), in order to probe the longitudinal MOKE generated by the in-plane magnetization component. Depending on the anisotropies and, therefore, on the magnetization components during the magnetization reversal process, one can detect an additional polar MOKE component, if the magnetization is not completely in-plane aligned. In order to probe the polar MOKE induced by the out-of-plane magnetization component, additional measurements in the polar geometry (out-of-plane external magnetic field) with perpendicular incident light are carried out (see the Supplemental Material [43]). Magneto-optic imaging of the surface domain structure is performed using an Evico-Zeiss Imager. A D2m polarizing microscope equipped with a LED light source provides a continuous spectrum of emitted light in the visible range. Magnetic contrast is obtained by digital image processing, in which the background image of the saturation state is subtracted from the sample image in remanence. Magnetic domains are observed after saturation of the sample and subsequent field decrease to zero.

The FMR is measured with a vector network analyzer (VNA, Rohde und Schwarz ZVB 40), which is attached to a grounded coplanar waveguide (GCPW). The samples are placed face down on the signal line of the GCPW and the transmission signal  $S_{21}$  is recorded. For the measurements, the frequency of the applied signal is swept across the resonance  $f_{\text{res}}$ , while a fixed in-plane magnetic field is applied. Using the resonance condition for a system with dominating shape anisotropy [44],

$$\Delta f(f) = (|\gamma|\mu_0\Delta H_0 + 2\alpha f)\sqrt{1 + \left(\frac{|\gamma|\mu_0 M_s}{2f}\right)^2}, \quad (1)$$

we can extract from the measured FMR frequency linewidth, the Gilbert damping  $\alpha$ , and the zero-field linewidth broadening. We use the  $M_s$  value determined by SQUID magnetometry and a fixed  $g$  factor of  $|\gamma|\hat{=} 28$  GHz/T.

### III. RESULTS AND DISCUSSION

We characterize the crystalline structure by XRD and our analysis of the YIG and Ce:YIG films reveals no secondary phases. The corresponding survey scans are shown in the Supplemental Material [43]. For Ce:YIG, it is significant that no  $\text{CeO}_2$  phase is detected, which could arise if the Ce concentration is too high [17,45]. From the positions of the film peaks, shown in Fig. 1, we obtain slightly larger values for the out-of-plane (OOP) lattice constant for YIG compared to the bulk value of 1.2376 nm [46,47]. Compared to unsubstituted YIG, the Ce:YIG samples show a 0.2 Å larger out-of-plane lattice constant, implying higher in-plane compressive strain for Ce:YIG on GGG compared to the low-strain state of YIG on GGG. The GGG substrates have a lattice constant of 1.2377 nm, which is slightly smaller than the literature value for GGG of 1.2383 nm [48]. The values derived from the  $\theta$ - $2\theta$  scans and the FWHM values of the film are given in Table I. Reciprocal-space-map (RSM) measurements of both Ce:YIG samples are shown in the Supplemental

Material [43]. They reveal a difference for in-plane lattice constants between substrate and film, which hint at a relaxation of the films.

For every film, we are able to observe Laue oscillations, indicating a good epitaxy of the samples. The Laue oscillations of the Ce:YIG samples show an obvious asymmetry, which is a sign of lattice relaxation due to the substrate-induced strain. A rocking curve analysis of the Ce:YIG (001) and (111) film peaks corroborates the high quality of the samples, by showing narrow single peaks with a FWHM of only  $0.022^\circ$  [GGG substrate peak FWHM ( $0.009 \pm 0.002$ ) $^\circ$ ] for both Ce:YIG films, comparable to the FWHM of the YIG films. The XRR analysis of the films, shown in Fig. 1(c), reveals pronounced fringes for all films, despite the large film thickness of around 100 nm, indicating very smooth surfaces. The dispersion and absorption values for the Ce:YIG films obtained from the XRR fits are in good agreement with the electron density calculated from the stoichiometry of  $\text{Ce}_1\text{Y}_2\text{Fe}_5\text{O}_{12}$  and the lattice constants determined from the XRD scans. From these fits, we obtain for all films a surface roughness below 1 nm and a higher roughness of around 2 nm for the substrate-film interface. A further surface analysis of the Ce:YIG samples, using atomic force microscopy (AFM), finds fully covered, droplet-free surfaces with a root mean square roughness of  $\sim 0.3$  nm for both crystallographic orientations. The AFM scans and rocking curve measurements of the Ce:YIG samples are shown in the Supplemental Material [43], while more information about the YIG film analysis and quality is provided in Ref. [40].

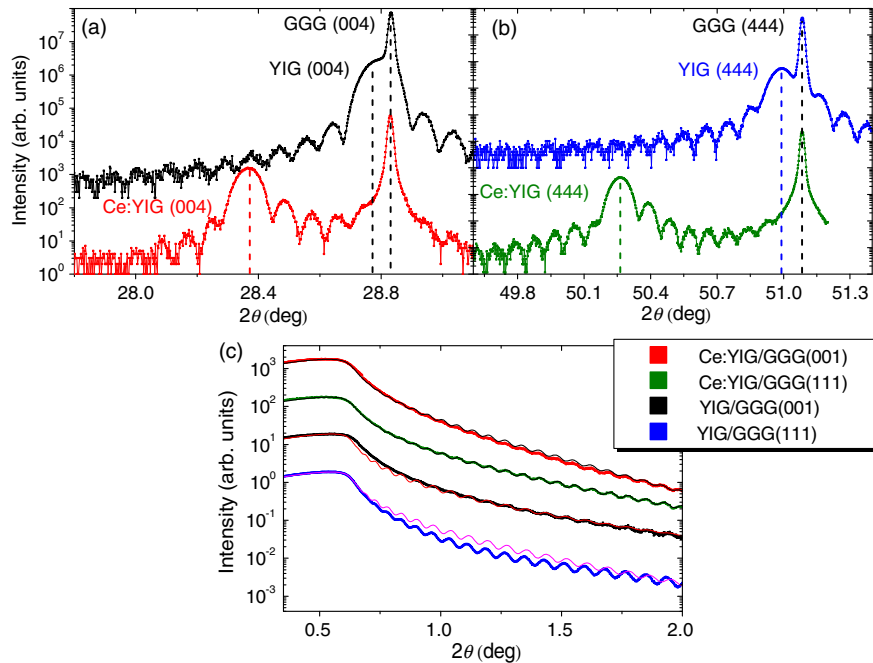


FIG. 1. XRD  $\theta$ - $2\theta$  scan of (a) YIG and Ce:YIG grown on GGG (001) and (b) YIG and Ce:YIG grown on GGG (111). (c) XRR measurement as a function of  $2\theta$  overlaid with the derived fit functions. The results of the thicknesses derived from the XRR fits are given in Table I. All films show a surface roughness below 1 nm.

TABLE I. Summary of the results from the XRD and XRR measurements.

Sample	Lattice spacing of	Film peak FWHM (mdeg)	Thickness (nm)	Surface roughness (nm)
	OOP reflection (nm) Error 0.001 (nm)			
YIG/GGG (001)	1.239	23.9 <sup>a</sup>	96	0.5
YIG/GGG (111)	1.240	21.9	97	0.8
Ce: YIG/GGG (001)	1.257	21.3	111	0.7
Ce: YIG/GGG (111)	1.257	22.8	112	0.7

<sup>a</sup>Film peak overlaps with the substrate peak.

Magnetization curves obtained by SQUID measurements are presented in Fig. 2(a) and the derived values, such as the saturation magnetic moment and coercive field, are given in Table II. While the magnetic moments of the YIG films are close to the literature value of 140 kA/m, the Ce-substituted films show an increased magnetic moment of around 155 kA/m. This larger value, compared to pure YIG, can be explained by the magnetic moment of the Ce<sup>3+</sup> ions that couple with the magnetic sublattices of the Fe<sup>3+</sup> ions. The Fe<sup>3+</sup> ions are themselves organized in two sublattices (*d* site and *a* site), which are antiferromagnetically coupled. The net moment is dominated by the *d* site for pure YIG. While the Y<sup>3+</sup> ions possess no magnetic moment, the Ce<sup>3+</sup> ions are aligned parallel to the *d*-site Fe<sup>3+</sup> ions, leading to a higher net magnetic moment

[17,49,50]. The higher moment furthermore confirms that no significant CeO<sub>2</sub> phase can be present within our films, as this would lower the moment [17].

Compared to the pure YIG films, both Ce:YIG samples show a larger coercive field that we detect within the resolution of our SQUID measurements. Since the coercive field is connected to the reversal mechanism of the magnetization, we next study the different contributions to the magnetic anisotropy in the Ce:YIG films, which play a key role in applications. The three main contributions to the magnetic free-energy density are  $f_{\text{sum}} = f_{\text{shape}} + f_{\text{cryst}} + f_{\text{uni}}$  contributing to the effective magnetic anisotropy and we consider these in the following analysis.  $f_{\text{shape}}$  denotes the demagnetization term from the shape anisotropy,  $f_{\text{cryst}}$  the contribution of the magnetocrystalline

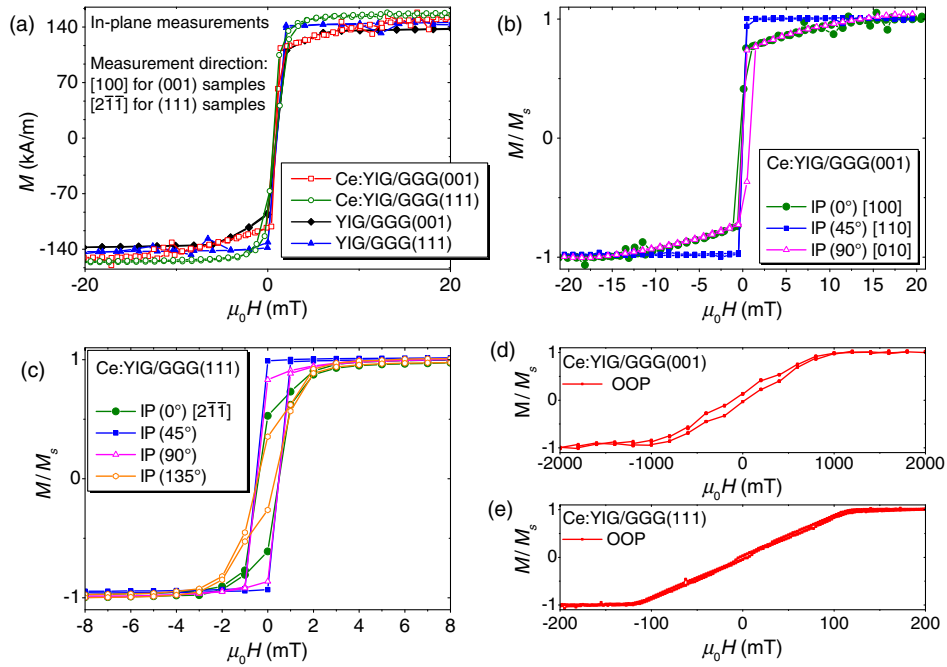


FIG. 2. (a) SQUID measurements at 300 K of magnetic moment as a function of the applied magnetic in-plane field. The paramagnetic contribution from the GGG substrate has been subtracted. The field is applied along the [100] direction for the samples with (001) orientation and along the  $[2\bar{1}\bar{1}]$  for the (111) samples. (b) In-plane SQUID loops for Ce:YIG/GGG(001) and (c) for Ce:YIG/GGG(111) as a function of the applied magnetic field. The in-plane *H*-field directions, with respect to the in-plane crystallographic axis of the samples, are given in the legends. The out-of-plane magnetization curves are shown for Ce:YIG/GGG(001) in (d) and for Ce:YIG/GGG(111) in (e).

TABLE II. Summary of the results from SQUID magnetometry.  $H_c$  denotes the coercive field,  $H_{s,IP}$  the in-plane and  $H_{s,OOP}$  out-of-plane saturation field determined for the hard axis. The angle marked behind the value denotes the in-plane orientation of the hard axis. The anisotropy constants are calculated from the anisotropy fields extracted from the SQUID measurements, using  $K_{\text{eff}} = \mu_0 M_s H_s / 2$ .

Sample	$M_s$ (kA/m)	$H_c$ (mT)	$H_{s,IP}$ (mT)	$K_{\text{eff},IP}$ (kJ/m <sup>3</sup> )	$H_{s,OOP}$ (T)	$K_{\text{eff},OOP}$ (kJ/m <sup>3</sup> )
YIG/GGG (001)	$139 \pm 7$	$<0.5$	$6.5 \pm 1$ (0°)	$0.5 \pm 0.1$		
YIG/GGG (111)	$144 \pm 7$	$<0.5$				
Ce:YIG/GGG (001)	$152 \pm 8$	$0.3 \pm 0.2$	$17.1 \pm 1$ (0°,90°)	$1.3 \pm 0.1$	$1 \pm 0.1$	$76 \pm 9$
Ce:YIG/GGG (111)	$158 \pm 8$	$0.5 \pm 0.1$	$5 \pm 1$ (135°)	$0.4 \pm 0.1$	$0.12 \pm 0.01$	$9.5 \pm 0.9$

energy, which in the case of YIG should yield a cubic anisotropy [51], and  $f_{\text{uni}}$  marks a uniaxial component, which can be induced by growth, stress, or interface effects in thin films. In general, pure YIG exhibits only a small magnetic anisotropy, which can be increased by a variation of the stoichiometry [52,53] or a growth-induced magnetoelastic contribution by selection of substrate lattice parameter [36].

To determine the influence of the cerium substitution, we perform in-plane angular-dependent SQUID, FMR, and VSM measurements. A more comprehensive discussion of the magnetic anisotropy and an overview of all angular-dependent scans are given in the Supplemental Material [43]. Here, we discuss the key results of these measurements and show, as an example, the angular dependence of the magnetization of the Ce:YIG samples determined by SQUID measurements, presented in Figs. 2(b) and 2(c).

The SQUID, VSM, and FMR measurements show a fourfold in-plane anisotropy for Ce:YIG films grown on GGG (001) substrates. One of the two easy axes of this cubic anisotropy is oriented along the [110] direction, while the hard axes can be found 45° tilted along [100] and [010]. The symmetry and orientation of anisotropy agrees with projection of the natural cubic anisotropy of the bulk YIG along the  $\langle 111 \rangle$  easy axes [51] to the sample plane. By comparing the saturation field  $H_s$  along the [100] direction with the one obtained for YIG/GGG(001), as shown in Fig. 2(a), we determine for YIG  $H_s = 7$  mT and for Ce:YIG  $H_s = 17$  mT. The further angular-dependent measurements, shown in the Supplemental Material [43], reveal an additional uniaxial in-plane magnetic anisotropy of  $H_u \leq 1$  mT, causing a contribution too weak to be resolved within the resolution of the SQUID measurements.

From the SQUID measurements, one only obtains the effective magnetization energy, given in Table II, which results from the sum of all contributing terms. Due to the small in-plane contribution of the uniaxial anisotropy, we can neglect this term, which allows us to use the SQUID saturation field values  $H_s$  to extract directly the cubic anisotropy constant from  $H_s$  measured along the hard axes [100] and [010], using  $K_{\text{cub}} = -H_s \mu_0 M_s / 2$  [51]. With this formula, we derive an increase of the cubic in-plane anisotropy by a factor of 3 compared to our pure YIG films, giving  $K_{\text{cub,Ce:YIG}} = (-1.3 \pm 0.1)$  kJ/m<sup>3</sup> and  $K_{\text{cub,YIG}} = (-0.5 \pm 0.1)$  kJ/m<sup>3</sup>.

The SQUID measurements of one of our Ce:YIG/GGG(111) samples reveal a magnetic hard axis along the 135° direction and an easier axis along 45°, compared to the 0° direction (which corresponds to the in-plane crystalline  $[2\bar{1}\bar{1}]$  orientation), as shown in Fig. 2(c). This symmetry indicates an in-plane uniaxial anisotropy contribution. The angular-dependent FMR measurements confirm this assumption as they yield an in-plane twofold symmetry for the anisotropy as well, hinting at a dominating in-plane uniaxial anisotropy. From the crystalline surface symmetry, one would expect a sixfold anisotropy, which is observed in VSM measurements of thinner samples [54]. The origin of the uniaxial anisotropy can be explained by the influence of the substrate surface as is evident from further XRD measurements, shown in the Supplemental Material [43].

The XRD measurements find a maximum for the miscut between the substrate normal and film orientation of only 0.1°, which matches with the orientation of the magnetic hard axis. These results highlight the importance of the substrate surface topography, as already a small miscut of only 0.1° can cause a dominating anisotropy term. This result is similar to earlier investigations for standard YIG films [55], for which a larger miscut was found to be the origin of an observed uniaxial magnetic anisotropy.

For the determination of the out-of-plane magnetization, we perform SQUID and polar MOKE magnetometry measurements, shown in Figs. 2(d), 2(e), and in more detail in the Supplemental Material [43]. For both crystalline orientations, we observe a hard-axis-like behavior of the magnetization. The out-of-plane SQUID measurement of Ce:YIG/GGG(001) sample yields a saturation field of  $H_s = (1.0 \pm 0.1)$  T, in good agreement with the FMR results. The origin of this anisotropy is a combination of surface, shape, and magnetoelastic anisotropy. The observed saturation field for Ce:YIG/GGG(111) of  $H_s = (120 \pm 10)$  mT is lower than the combination of shape and uniaxial in-plane anisotropy, indicating a further contribution of an anisotropy favoring an out-of-plane magnetization.

The origin of this complex anisotropy behavior possibly results from the epitaxial growth on the GGG substrate having a smaller in-plane lattice constant, leading to a magnetoelastic contribution to the anisotropy. RSM measurements indicate that the Ce:YIG films undergo

relaxation as the film thickness increases, making an estimation of the magnetoelastic contribution difficult due to an inhomogeneous strain within the layer thickness. Further studies of thinner, nonrelaxed Ce:YIG films should aim to determine the influence of the Ce substitution in combination with epitaxial growth on substrates with a smaller in-plane lattice constant, such as yttrium aluminum garnet (YAG) [36]. In combination with a variation of the Ce amount, this might allow one to increase the out-of-plane magnetic anisotropy and still maintain epitaxial growth but this is beyond the scope of the work presented here. Using these methods, it should be possible to adapt the anisotropy to satisfy the requirements of the desired application, such as a magneto-optic sensor [39].

Next we describe the magneto-optic properties of the Ce:YIG. Figure 3(a) shows drastically increased MOKE signals for Ce:YIG compared to pure YIG for a wavelength of  $\lambda = 635$  nm. While the magnitude of the Kerr rotation of YIG at this wavelength is below 2 mdeg for both orientations, it increases to 26 mdeg for Ce:YIG/GGG(001) and to 38 mdeg for Ce:YIG/GGG(111). As seen in Fig. 3(b), at  $\lambda = 406$  nm, we observe a larger Kerr magnitude of 16 mdeg for both YIG samples. Ce:YIG shows an even larger effect with a Kerr rotation of 37 mdeg for (001) and 46 mdeg for (111), i.e., the Ce:YIG exhibits a 200% higher signal compared to YIG. Bulk YIG has a band

gap of 2.66 eV  $\hat{=}$  466 nm and a similar band gap is present for Ce:YIG [20].

These MOKE results show that the enhancement of the magneto-optic constants, known from the Faraday effect for Ce:YIG [19–22], is also present for the Kerr effect, which makes Ce:YIG a useful material for nonreciprocal devices. Furthermore the substitution by cerium expands the range of usable wavelengths far into the optical wavelength region, allowing us to use optically operated devices in reflection geometry for the readout of the magnetic structure, including high-resolution MOKE microscopy.

Using the enhanced MOKE results, we now compare the magnetic anisotropy information from MOKE hysteresis and domain images with the results obtained by the SQUID measurements. For both wavelengths, a noticeable difference in the hysteresis loops between the two crystalline orientations of Ce:YIG can be observed. Ce:YIG/GGG(111) shows higher MOKE signals than Ce:YIG/GGG(001) for both wavelengths, and larger coercive fields for (111) vs (001), which is the opposite trend compared to the SQUID results.

The MOKE measurements for YIG and Ce:YIG on GGG(001) are done with an external magnetic field along the [110] direction, and the hysteresis loop has the same high squareness as in the [110] SQUID measurements, shown in Fig. 2(c). The longitudinal MOKE microscopy

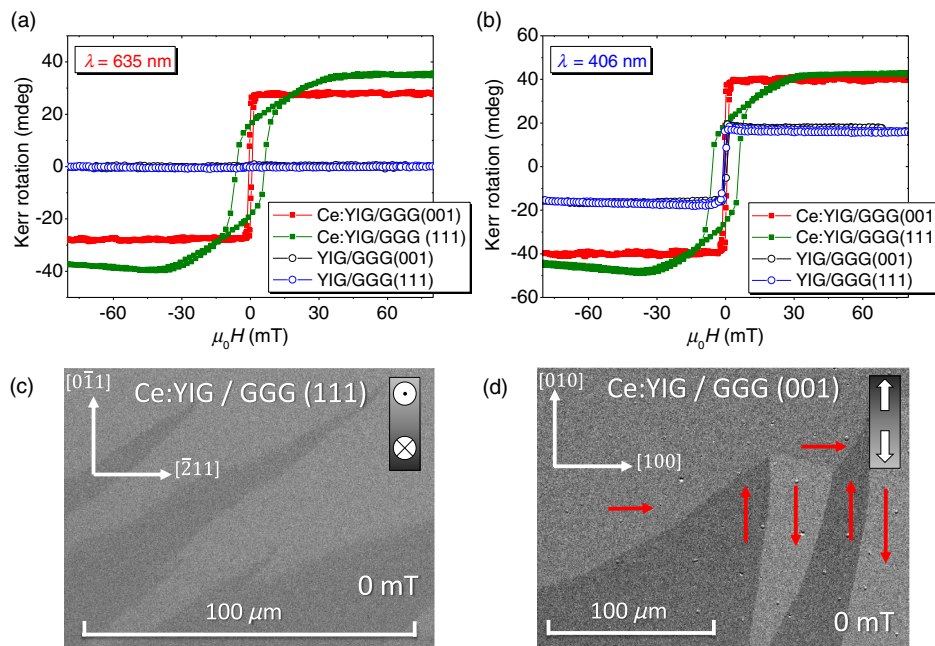


FIG. 3. (a),(b) MOKE signal of YIG and Ce:YIG as a function of the applied magnetic field for laser wavelengths of (a)  $\lambda = 635$  nm and (b)  $\lambda = 406$  nm. The MOKE signals are recorded for Ce:YIG/GGG(001) with the external magnetic fields along the [110] direction and for Ce:YIG/GGG(111) along the  $[2\bar{1}\bar{1}]$  direction. From the MOKE loops, we extract  $H_c = (0.7 \pm 0.1)$  mT for Ce:YIG/GGG(001),  $H_c = (5.8 \pm 0.3)$  mT for Ce:YIG/GGG(111),  $H_c = (0.5 \pm 0.1)$  mT for YIG/GGG(001), and  $H_c = (0.5 \pm 0.1)$  mT for YIG/GGG(111). (c),(d) MOKE microscopy image of the boundary between the magnetic domain structures that result from the different anisotropies in (c) the Ce:YIG/GGG(111) sample observed in a polar MOKE configuration and (d) the Ce:YIG/GGG(001) sample observed by longitudinal MOKE. The red arrows correspond to the alignment of the in-plane magnetization.

images presented in Fig. 3(d) show a domain pattern that can be explained by a fourfold in-plane anisotropy, in combination with a twofold anisotropy [56], which is consistent with the lattice symmetry and the SQUID and FMR data, shown in the Supplemental Material [43].

Finally, it is important to mention a symmetric contribution with respect to the external magnetic field for the magnetization curves of the YIG samples at  $\lambda = 406$  nm in Fig. 3(b). As reported, for example, for Co-based Heusler compounds [57], this effect is generated by quadratic MOKE contributions and deforms the magnetization curves.

The MOKE hysteresis for the Ce:YIG/GGG(111) sample is measured along  $[2\bar{1}\bar{1}]$ . The different loop shape compared to the SQUID data is most likely a result of contributions of the out-of-plane magnetization component (and, therefore, of the polar MOKE) to the longitudinal MOKE signals [58], as the measurements are taken under  $45^\circ$  angle of incidence. A polar MOKE microscopy image, shown in Fig. 3(c), reveals a domain structure indicating a nonzero remanence in the out-of-plane direction. The observed domain shape is consistent with the presence of an in-plane uniaxial anisotropy.

The enhanced magneto-optic contrast allows us to verify our SQUID results for the magnetic anisotropy. Furthermore, the enhanced contrast shows that the Ce substitution allows one to investigate the magnetic domain structure even in thin films. Such investigations are of particular interest because garnets are known for more

complex domain structures, for example, for the formation of magnetic bubble skyrmions [59]. Having established the magnetostatic properties, one needs to study the spin dynamics and, in particular, the damping parameter of the material, in order to be able to use the material in spintronic devices.

In order to provide the missing information of the spin dynamics, we finally study the magnetodynamic properties to gauge the high-frequency performance of Ce:YIG. FMR response as a function of the frequency is presented for Ce:YIG in Fig. 4(a) and for YIG in Fig. 4(b). Despite the fact that all of our films have a similar thickness of approximately 100 nm, the Ce:YIG shows, in general, more than 1 order of magnitude lower FMR peak and 2 orders of magnitude wider resonance linewidths. This leads to the experimental challenge that the FMR signals of the Ce:YIG are comparable to those of the paramagnetic background signal caused by the GGG substrates, which makes it necessary to consider a linear contribution for the resonance peak for high magnetic fields.

Fitting a Lorentz peak function to the absolute signal, we obtain the FMR linewidth plotted in Fig. 4(c). As the slope of  $\Delta f$  is only slightly affected by any magnetic anisotropy, Eq. (1) allows us to extract a good estimate of the Gilbert damping of the material, as shown in Table III. For our 100-nm-thick YIG films, we observe a difference between the two crystalline orientations. While the Gilbert damping constant  $\alpha$  is  $2.6 \times 10^{-4}$  for the (001) orientation, the damping as well as  $\Delta H_0$  are increased by a factor of 2 for

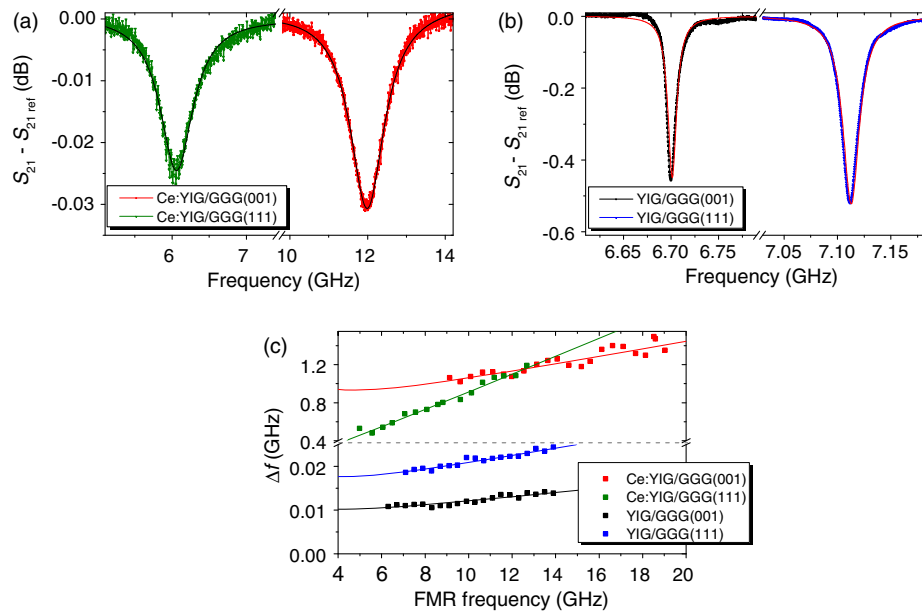


FIG. 4. (a) FMR signal as a function of frequency for (a) Ce:YIG at an external magnetic field of  $\mu_0 H = 160$  mT and for (b) YIG at an external magnetic field of  $\mu_0 H = 170$  mT. The fitted Lorentz peak function is superposed. From the fit, we obtain a FWHM of 1.07 GHz for Ce:YIG(001), 0.54 GHz for Ce:YIG(111), 11.1 MHz for YIG(001), and 18.7 MHz for YIG(001). (c) FMR frequency linewidth  $\Delta f_{\text{res}}$  as a function of FMR frequency  $f_{\text{res}}$  combined with the derived fit functions of Eq. (1). The data are obtained for an external magnetic field along the [100] direction for samples with the (001) orientation and along  $[2\bar{1}\bar{1}]$  for the (111) samples.



TABLE III. Summary of the results from FMR measurements. The resonance fits based on Eq. (1) use the  $M_s$  obtained from SQUID measurements, given in Table II.

Sample	$\mu_0\Delta H_0$ (mT)	$\alpha(10^{-4})$
YIG/GGG (001)	$0.24 \pm 0.04$	$2.6 \pm 0.4$
YIG/GGG (111)	$0.41 \pm 0.06$	$4.4 \pm 0.7$
Ce:YIG/GGG (001)	$22 \pm 4$	$200 \pm 40$
Ce:YIG/GGG (111)	$-2.9 \pm 3$	$480 \pm 70$

the (111) orientation. The exact values are given in Table III. We expect that the enhanced damping is the result of a more complex growth condition for the (111) interface and lower crystalline perfection, which would need further optimization, while the value for the (001) oriented film is remarkably low [40].

Both Ce:YIG samples show 2 orders of magnitude higher Gilbert damping, on the order of  $10^{-2}$ , as well as increased zero-field broadening compared to YIG. The observed increase by 2 orders of magnitude for  $\alpha$  can be explained as a sum of different contributions. First, the  $\text{Ce}^{3+}$  substitution leads to an expanded crystal lattice, which also affects the Fe sublattice, and leads to tetragonal distortion in the epitaxial films on GGG. Second, the magnetic moment carried by the  $\text{Ce}^{3+}$  leads to a perturbation of the Fe sublattices. Third, the  $\text{Ce}^{3+}$  substitution, which only occupies one third of the lattice sites and is not expected to be ordered, will lead to different environments for the Fe ions. Similarly to the pure YIG films, we also find a noticeable increase of  $\alpha$  for Ce:YIG(111) compared to the (001) orientation. Again, this result hints at a more complex growth condition on the GGG(111) substrates. For the zero-field broadening of the Ce:YIG films we obtain a slightly different behavior for the (001) orientation where a clear increase of  $\Delta H_0$  is seen, and for the (111) direction, where we find zero broadening (the determined negative value  $\Delta H_0$  is compatible within the error bars to a zero broadening as no negative value is expected). Despite the higher damping in the insulating Ce:YIG films, we can still observe a clear FMR signal [15] and damping that is similar to magnetic metals [60,61]. This damping constant is low enough to allow for fast switching in competitive devices. Furthermore, as Ce:YIG maintains the good insulating properties of YIG, no Ohmic losses, for instance, due to eddy currents occur and magnonic spin currents can propagate with ultralow power dissipation.

#### IV. CONCLUSION

The crystalline, magneto-optic, and magnetic properties of Ce:YIG films on GGG are determined for (001) and (111) crystallographic orientations and compared with those of YIG films. The XRD curves of the Ce:YIG samples show Laue oscillations, a surface roughness below 1 nm, and very narrow rocking curves of  $0.022^\circ$ , indicating

high crystalline quality, but also a lattice strain induced by the mismatch with the GGG substrates. Our SQUID measurements show that Ce substitution only slightly increases the total magnetic moment by 10 kA/m. All magnetic characterization methods used reveal that the substitution by Ce causes a higher magnetic anisotropy compared to pure YIG, which, in the case of Ce:YIG/GGG(001), has a fourfold in-plane component and a more complex anisotropy for the Ce:YIG/GGG(111), showing that anisotropies can be tailored in this material. The spin dynamics are studied by VNA-FMR and measurements of the thin films reveal that our high-quality films exhibit a magnetic damping comparable to magnetic metals of  $\alpha = 4 \times 10^{-2}$ . In contrast to the usual magneto-optic investigation of garnets, which focuses on the Faraday effect, we study the magneto-optic Kerr effect. The usage of the Kerr effect enables thin film magneto-optic devices, which are desirable for the design of integrated magneto-optic devices such as isolators [9,62,63] or circulators [7]. In particular, MOKE measurements of Ce:YIG reveal an increase of a factor of 2 of the Kerr rotation for  $\lambda = 406$  nm, compared to YIG, and a tenfold increase of the Kerr rotation for  $\lambda = 635$  nm. This investigation of the MOKE in this material shows that the MOKE is significant for both wavelengths demonstrating the broader applicability of this material for magneto-optic devices, like sensors [38,39], allowing for high resolution magneto-optic imaging. Our magnetic microscopy reveals a strong contrast for the different magnetic domain orientations, highlighting that, in addition to applications, this insulating material provides an excellent research basis for investigation of complex magnetic phenomena like the magneto-optic imaging of magnetostatic spin-wave eigenmodes [24,25] and domain-wall motion due to magnonic spin currents [28,33]. Our results show that, by using the Ce substitution of YIG for tailoring the magnetic properties and magneto-optic properties, one obtains an improved toolkit for engineering magnetic properties, based on the demands of applications.

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